DESCRIPTION

The VLMW32.. white LED is an advanced product in terms of heat dissipation.

The leadframe profile of this PLCC-4 SMD package is optimized to reduce the thermal resistance.

This allows higher drive current and doubles the light output compared to Vishay's high intensity SMD LED in PLCC-2 standard package.

PRODUCT GROUP AND PACKAGE DATA

- Product group: LED
- Package: SMD PLCC-4
- · Product series: power
- Angle of half intensity: ± 60°

PARTS TABLE		
PART	COLOR, LUMINOUS INTENSITY	TECHNOLOGY WAVELENGTH
VLMW3200-GS08	White, $I_V \ge 560 \text{ mcd}$ (typ 900 mcd)	INGaN/TAG in SiC
VLMW3201-GS08	White, $I_V \ge 710 \text{ mcd}$	INGaN/TAG in SiC

FEATURES

Power SMD LED PLCC-4

- High efficient INGaN technology
- Available in 8 mm tape
- · Luminous intensity, color and forward voltage categorized per packing unit
- · Luminous intensity ratio per packing unit $I_{Vmax}/I_{Vmin} \le 1.6$
- ESD class 1
- · Suitable for all soldering methods according to CECC
- · Lead (Pb)-free device
- Preconditioning: according to JEDEC level 2a

APPLICATIONS

- Interior and exterior lighting
- · Indicator and backlighting purposes for audio, video, LCD's switches, symbols, illuminated advertising etc.
- Illumination purpose, alternative to incandescent lamps
- General use







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VLMW320.

Vishay Semiconductors





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PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Reverse voltage 2)		V _R	5	V	
DC Forward current	$T_{amb} \le 65 \ ^{\circ}C$	I _F	30	mA	
Surge forward current	$t_p \leq 10 \ \mu s$	I _{FSM}	0.1	А	
Power dissipation		PV	127	mW	
Junction temperature		Tj	100	°C	
Operating temperature range		T _{amb}	- 40 to + 100	°C	
Storage temperature range		T _{stg}	- 40 to + 100	°C	
Soldering temperature	t ≤ 5 s	T _{sd}	260	°C	
Thermal resistancemounted on PC boardjunction/ambient(pad design see page 6)		R _{thJA}	270	K/W	

Note:

¹⁾ $T_{amb} = 25 \,^{\circ}C$, unless otherwise specified ²⁾ Driving the LED in reverse direction is suitable for a short term application

PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Luminous intensity ²⁾	I _F = 30 mA	VLMW3200	IV	560			mcd
		VLMW3201	Ι _V	710	900		mcd
Chromaticity coordinate x, y acc. to CIE 1931	I _F = 30 mA	VLMW320.	x y		0.33 0.33		
Angle of half intensity	I _F = 30 mA		φ		± 60		deg
Forward voltage	I _F = 30 mA		V _F		3.7	4.2	V
Reverse voltage	I _R = 10 μA		V _R	5			V
Temperature coefficient of V _F	I _F = 20 mA		TC _{VF}		- 4		mV/K
Temperature coefficient of IV	I _F = 20 mA		TCIV		- 0.5		%/K

Note:

⁽¹⁾ $T_{amb} = 25$ °C, unless otherwise specified ⁽²⁾ In one Packing Unit I_{Vmax}./I_{Vmin}. ≤ 1.6

LUMINOUS INTENSITY CLASSIFICATION				
GROUP	LIGHT INTENSITY (mcd)			
STANDARD	MIN.	MAX.		
U2	560	710		
V1	710	900		
V2	900	1120		
AA	1120	1400		
AB	1400	1800		
BA	1800	2240		
BB	2240	2800		

Note:

Luminous intensity is tested at a current pulse duration of 25 ms and an accuracy of ± 11 %.

The above type numbers represent the order groups which include only a few brightness groups. Only one group will be shipped on each reel (there will be no mixing of two groups on each reel).

In order to ensure availability, single brightness groups will not be orderable.

In a similar manner for colors where wavelength groups are measured and binned, single wavelength groups will be shipped on any one reel.

In order to ensure availability, single wavelength groups will not be orderable.

CROSSING TABLE				
VISHAY	OSRAM	NICHIA		
VLMW3200	LWE67C-U2V2	NSCW021T		
VLMW3201	LWE67C-V1V2	NSCW021T		



CHROMATICITY COORDINATED GROUPS FOR WHITE SMD LED						
	X	Y			X	Y
	0.291	0.291 0.268		0.330	0.330	
5L -	0.285	0.279		7L	0.330	0.347
	0.307	0.312			0.347	0.371
	0.310 0.297		0.345	0.352		
	0.296 0.259			0.330	0.310	
5K	0.291	0.268		7К	0.330	0.330
	0.310	0.297			0.338	0.342
	0.313	0.284			0.352	0.344
	0.310	0.297			0.345	0.352
	0.307	0.312		8L	0.347	0.371
6L	0.330	0.347			0.367	0.401
	0.330	0.330			0.364	0.380
6К -	0.313	0.284			0.352	0.344
	0.310	0.297		8K	0.338	0.342
	0.330	0.330		or	0.364	0.380
	0.330	0.310			0.360	0.357

Note:

Chromaticity coordinate groups are tested at a current pulse direction of 25 ms and a tolerance of \pm 0.01.

TYPICAL CHARACTERISTICS

T_{amb} = 25 °C, unless otherwise specified

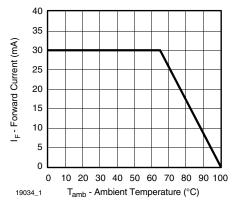


Figure 1. Forward Current vs. Ambient Temperature

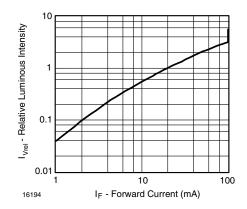


Figure 2. Relative Luminous Intensity vs. Forward Current

VLMW320.

Vishay Semiconductors



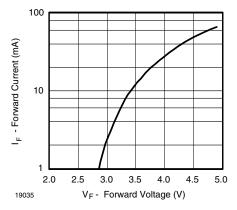


Figure 3. Forward Current vs. Forward Voltage

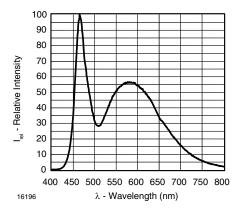


Figure 4. Relative Intensity vs. Wavelength

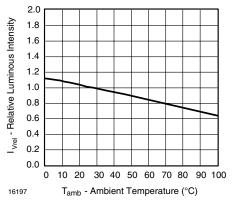


Figure 5. Relative Luminous Intensity vs. Ambient Temperature

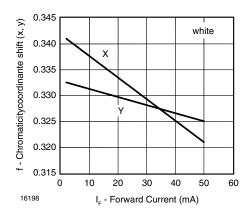


Figure 6. Chromaticity Coordinate Shift vs. Forward Current

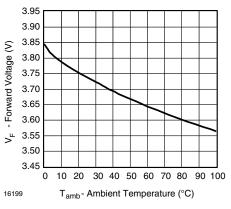


Figure 7. Forward Voltage vs. Ambient Temperature

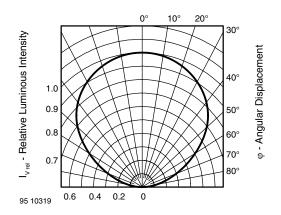


Figure 8. Relative Luminous Intensity vs. Angular Displacement

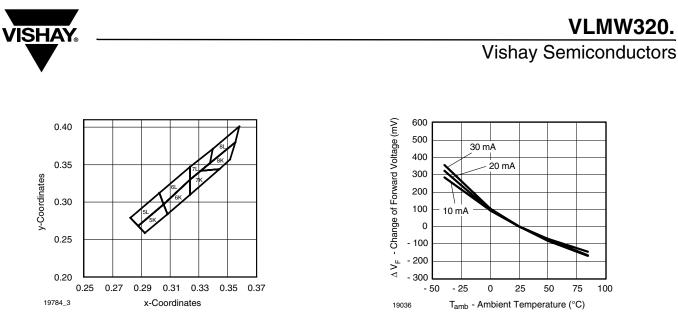
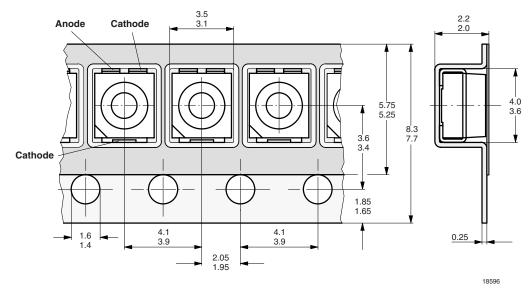


Figure 9. White Grouping SMD

Figure 10. Change of Forward Voltage vs. Ambient Temperature

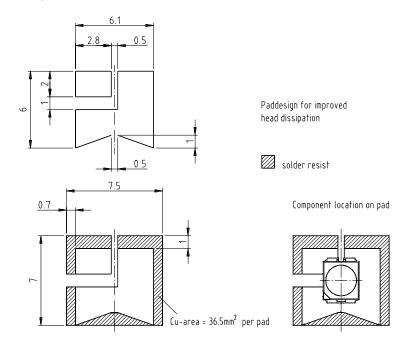
TAPING Dimensions in millimeters





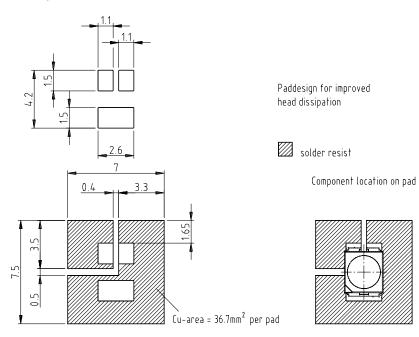
RECOMMENDED PAD DESIGN Dimensions in millimeters

(Wave-soldering), R_{THJA} = 270 K/W



RECOMMENDED PAD DESIGN Dimensions in millimeters

(Reflow-soldering), R_{THJA} = 270 K/W



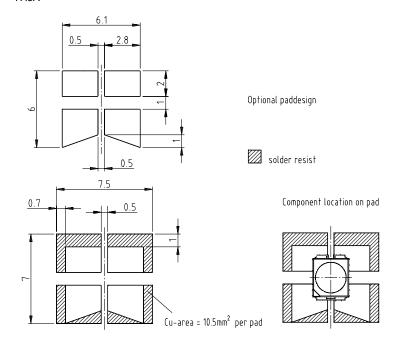
16261

16260



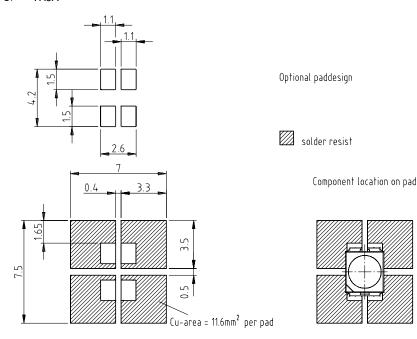
OPTIONAL PAD DESIGN Dimensions in millimeters

(Wave-soldering), R_{THJA} = 290 K/W



OPTIONAL PAD DESIGN Dimensions in millimeters

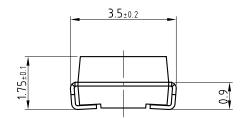
(Reflow-soldering), $R_{THJA} = 290 \text{ K/W}$

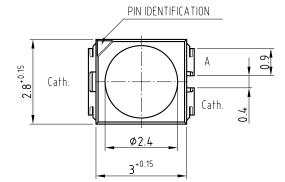


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PACKAGE DIMENSIONS in millimeters



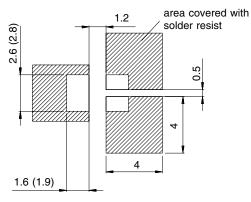


Drawing-No. : 6.541-5054.01-4 Issue: 3; 31.03.08



ISHA

Mounting Pad Layout

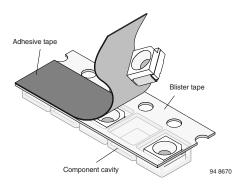


Dimensions: IR and Vaporphase (Wave soldering)

METHOD OF TAPING/POLARITY AND TAPE AND REEL

SMD LED (VLM.3-SERIES)

Vishay's LEDs in SMD packages are available in an antistatic 8 mm blister tape (in accordance with DIN IEC 40 (CO) 564) for automatic component insertion. The blister tape is a plastic strip with impressed component cavities, covered by a top tape.



TAPING OF VLM.3...

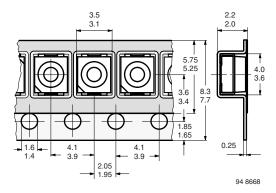


Figure 11. Tape Dimensions in mm for PLCC-2









REEL PACKAGE DIMENSION IN MILLIMETERS FOR SMD LEDS, TAPE OPTION GS08 (= 1500 PCS.)

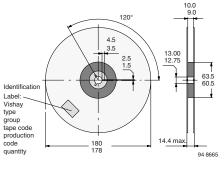


Figure 12. Reel Dimensions - GS08

SOLDERING PROFILE

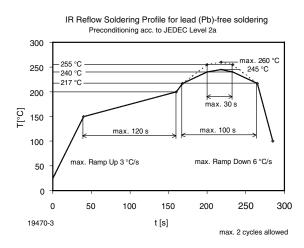


Figure 13. Vishay Lead (Pb)-free Reflow Soldering Profile (acc. to J-STD-020C)

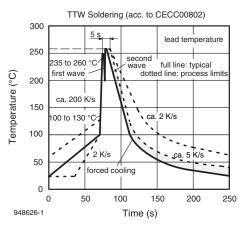
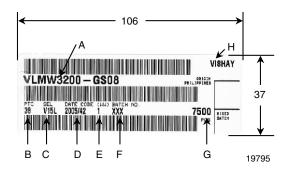


Figure 14. Double Wave Soldering of Opto Devices (all Packages)

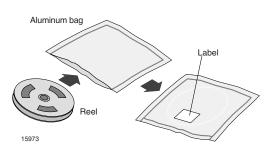
BAR CODE PRODUCT LABEL EXAMPLE:



- A) Type of component
- B) Manufacturing plant
- C) SEL selection code (bin): e.g.: V1 = code for luminous intensity group 5L = code for chrom. coordinate group
- D) Date code year/week
- E) Day code (e. g. 1: Monday)
- F) Batch no.
- G) Total quantity
- H) Company code

DRY PACKING

The reel is packed in an anti-humidity bag to protect the devices from absorbing moisture during transportation and storage.



FINAL PACKING

The sealed reel is packed into a cardboard box. A secondary cardboard box is used for shipping purposes.

RECOMMENDED METHOD OF STORAGE

Dry box storage is recommended as soon as the aluminum bag has been opened to prevent moisture absorption. The following conditions should be observed, if dry boxes are not available:

- Storage temperature 10 °C to 30 °C
- Storage humidity ≤ 60 % RH max.

After more than 672 h under these conditions moisture content will be too high for reflow soldering.

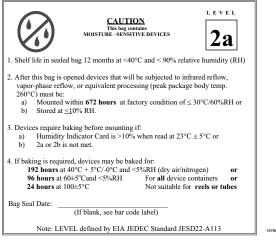
In case of moisture absorption, the devices will recover to the former condition by drying under the following condition:

192 h at 40 °C + 5 °C/- 0 °C and < 5 % RH (dry air/nitrogen) or

96 h at 60 $^{\circ}\text{C}$ + 5 $^{\circ}\text{C}$ and < 5 % RH for all device containers or

24 h at 100 °C + 5 °C not suitable for reel or tubes.

An EIA JEDEC standard JESD22-A112 level 2a label is included on all dry bags.



Example of JESD22-A112 level 2a label

ESD PRECAUTION

Proper storage and handling procedures should be followed to prevent ESD damage to the devices especially when they are removed from the antistatic shielding bag. Electro-static sensitive devices warning labels are on the packaging.



OZONE DEPLETING SUBSTANCES POLICY STATEMENT

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively.
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA.
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany



Vishay

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